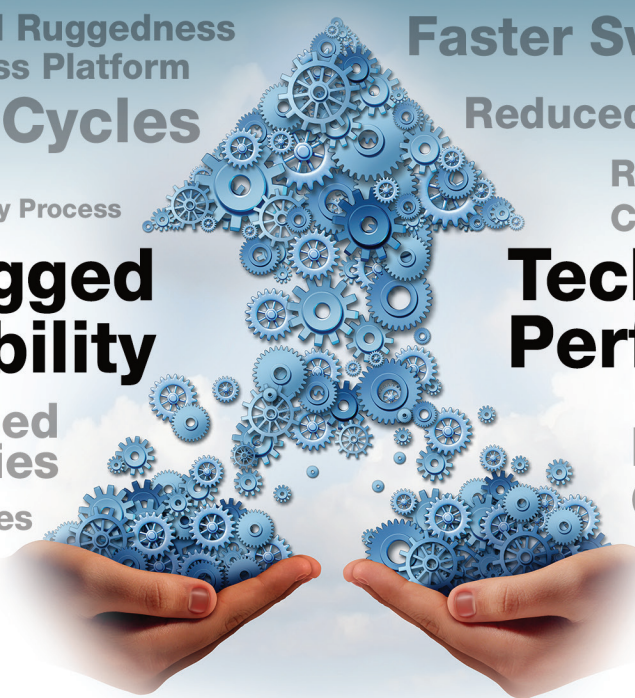




3 V to 16 V **Enhanced** Analog Switches and Multiplexers



Enhanced Ruggedness
Proven Process Platform
Long Life Cycles
Higher ESD Capability
High-Density Process

Enhanced Ruggedness
Proven Process Platform
Long Life Cycles
Higher ESD Capability
High-Density Process

Reduced Lead Times
Increased Voltage up to 16 V
High Latch-Up Current

Rugged Reliability

Established Factories

Reduced Power Consumption
Reduced Parasitic Capacitance

Technology Performance

Lower Switch On-Resistance
Low Leakage

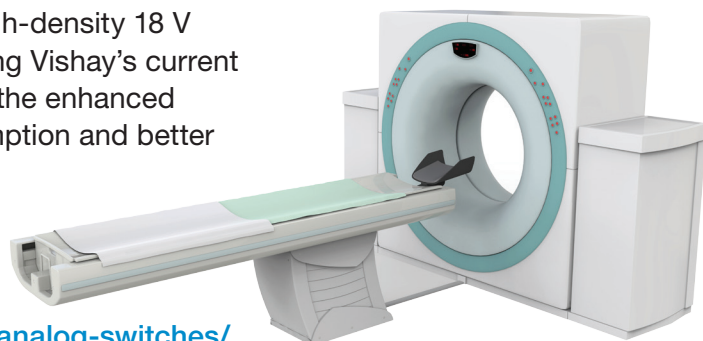
Vishay Siliconix, inventor of the analog switch, continues to develop new products and drive innovation with a new line of enhanced analog switches and multiplexers.



APPLICATIONS:

- Test equipment and data acquisition
- Audio and video signal routing
- Industrial process control and automation
- Medical and healthcare equipment
- Communication systems

The new enhanced products, designed on a proven high-density 18 V BCD process, offer an upgrade path for customers using Vishay's current 12 V series products. Through improved performance, the enhanced family addresses requirements for lower power consumption and better precision in sensitive analog designs.



For more information, please visit: www.vishay.com/analog-switches/

Contact: analogswitchtechsupport@vishay.com

DG408LE, DG409LE

Enhanced Performance Products



Enhanced Performance

- Extended operation to 16 V single power supply and ± 8 V dual power supplies
- Lower switch on-resistance with improved tolerance
- Reduced switch leakage limits by 50 %
- Enhanced ESD / HBM from 2 kV to 2.5 kV
- Enhanced latch-up capability from 200 mA to 300 mA

Applications

- Automatic test equipment
- Data acquisition systems
- Meters and instruments
- Medical and healthcare systems
- Portable Meter

New Products are Pin-Compatible with Current DG408L, DG409L Series:

PACKAGE	EXISTING PART NUMBER	NEW ENHANCED PART NUMBER	EXISTING PART NUMBER	NEW ENHANCED PART NUMBER
TSSOP16	DG408LDQ-E3	DG408LEDQ-GE3	DG409LDQ-E3	DG409LEDQ-GE3
	DG408LDQ-T1-E3	DG408LEDQ-T1-GE3	DG409LDQ-T1-E3	DG409LEDQ-T1-GE3
SOIC16	DG408LDY-E3	DG408LEDY-GE3	DG409LDY-E3	DG409LEDY-GE3
	DG408LDY-T1-E3	DG408LEDY-T1-GE3	DG409LDY-T1-E3	DG409LEDY-T1-GE3
QFN16		DG408LEDN-T1-GE4		DG409LEDN-T1-GE4

Specification Comparison Table (Single 12 V):

PARAMETER	TEMP	DG408L, DG409L			DG408LE, DG409LE			UNIT
		TYP	MIN	MAX	TYP	MIN	MAX	
Analog Switch								
Drain-Source On-Resistance	Room	17		29			23	Ω
	Full			35			27	
On-Resistance Flatness	Room	3		7			6.5	Ω
Switch Off Leakage Current I _{S(off)}	Room		-1	1				nA
	Full		-10	10		-5	5	
Switch Off Leakage Current I _{D(off)}	Room		-1	1				nA
	Full		-10	10		-5	5	
Channel On Leakage Current I _{D(on)}	Room		-1	1				nA
	Full		-10	10		-5	5	
Dynamic Characteristics								
Transition Time	Room	30		60	85		100	ns
	Full			65			110	
Break-Before-Make Time	Room	11	1		34			ns
	Full							
Enable Turn-On Time	Room	38		55	55		72	ns
	Full			60			82	
Enable Turn-Off Time	Room	18		25	36		47	ns
	Full			30			50	
Charge Injection (DG408L)	Full	1		5	-11		-	pC
Charge Injection (DG409L)	Full				-10			
Off Isolation (DG408L)	Full	-70			-99			dB
Off Isolation (DG409L)	Full				-87			
Crosstalk (DG408L)	Full	-82			-98			dB
Crosstalk (DG409L)	Full				-109			
Source Off Capacitance (DG408L)	Full				5.5			pF
Source Off Capacitance (DG409L)	Full	7			5.5			
Drain Off Capacitance (DG408L)	Full				25			pF
Drain Off Capacitance (DG409L)	Full	20			13.5			
Drain On Capacitance (DG408L)	Full				35			pF
Drain On Capacitance (DG409L)	Full	31			23.5			
Power Supplies								
Power Supply Range	Full		3	12				V
Power Supply Current	Room	0.2		0.7	3.5		6	μA

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT WWW.VISHAY.COM/DOC/91000



DG411LE, DG412LE, DG413LE

Enhanced Performance Products

Enhanced Performance

- Extended operation to 16 V single power supply and ± 8 V dual power supplies from current 12 V and ± 6 V, respectively
- Enhanced ESD / HBM from 2 kV to 2.5 kV
- Enhanced latch-up capability from 200 mA to 400 mA

Applications

- Automatic test equipment
- Data acquisition systems
- Meters and instruments
- Medical and healthcare systems
- Communication systems
- Portable Meters

New products are pin-compatible with current DG411L, DG412L, DG413L series:

PACKAGE	EXISTING PART NUMBER	NEW ENHANCED PART NUMBER	EXISTING PART NUMBER	NEW ENHANCED PART NUMBER	EXISTING PART NUMBER	NEW ENHANCED PART NUMBER
PDIP16	DG411LDJ-E3	DG411LEDJ-GE3	DG412LDJ-E3	DG412LEDJ-T1-GE3	DG413LDJ-E3	DG413LEDJ-GE3
TSSOP16	DG411LDQ-E3	DG411LEDQ-GE3	DG412LDQ-E3	DG412LEDQ-GE3	DG413LDQ-E3	DG413LEDQ-GE3
TSSOP16	DG411LDQ-T1-E3	DG411LEDQ-T1-GE3	DG412LDQ-T1-E3	DG412LEDQ-T1-GE3	DG413LDQ-T1-E3	DG413LEDQ-T1-GE3
SOIC16	DG411LDY-E3	DG411LEDY-GE3	DG412LDY-E3	DG412LEDY-GE3	DG413LDY-E3	DG413LEDY-GE3
SOIC16	DG411LDY-T1-E3	DG411LEDY-T1-GE3	DG412LDY-T1-E3	DG412LEDY-T1-GE3	DG413LDY-T1-E3	DG413LEDY-T1-GE3

Specification Comparison Table (Single 12 V):

Parameter	TEMP	DG411L, DG412L, DG413L				DG411LE, DG412LE, DG413LE			
		TYP	MIN	MAX	UNIT	TYP	MIN	MAX	UNIT
Analog Switch									
Analog Signal Range	Full		0	12	V		0	12	V
Drain-Source On-Resistance	Room	20		30	Ω	16		30	Ω
	-40 °C to 85 °C			40				40	
	-55 °C to 125 °C			45				45	
Dynamic Characteristics									
Turn-On Time	Room	20		50	ns	16		50	ns
	-40 °C to 85 °C			60				60	
	-55 °C to 125 °C			70				70	
Turn-Off Time	Room	12		30	ns	9		30	ns
	-40 °C to 85 °C			40				40	
	-55 °C to 125 °C			48				48	
Break-Before-Make Time Delay	Room	6			ns	5			ns
	-40 °C to 85 °C								
	-55 °C to 125 °C								
Charge Injection	Room	5			pC	6.6			pC
Off Isolation	Room	71			dB	68.4			dB
Crosstalk	Room	95			dB	114			dB
Source Off Capacitance	Room	5			pF	5			pF
Drain Off Capacitance	Room	6			pF	6			pF
Drain On Capacitance	Room	15			pF	15			pF

DG441LE, DG442LE

Enhanced Performance Products

Enhanced Performance

- Extended operation to 16 V single power supply and ± 8 V dual power supplies
- Lower switch on-resistance with improved tolerance
- Reduced switch leakage limits by 50 %
- Enhanced ESD / HBM from 2 kV to 2.5 kV
- Enhanced latch-up from 200 mA to 400 mA

Applications

- Automatic test equipment
- Process control and automation
- Data acquisition systems
- Meters and instruments
- Medical and healthcare systems
- Communication systems



PACKAGE	EXISTING PART NUMBER	NEW ENHANCED PART NUMBER
PDIP16	DG441LDJ-E3	DG441LEDJ-GE3
TSSOP16	DG441LDQ-E3	DG441LEDQ-GE3
	DG441LDQ-T1-E3	DG441LEDQ-T1-GE3
SOIC16	DG441LDY-E3	DG441LEDY-GE3
	DG441LDY-T1-E3	DG441LEDY-T1-GE3

EXISTING PART NUMBER	NEW ENHANCED PART NUMBER
DG442LDJ-E3	DG442LEDJ-GE3
DG442LDQ-E3	DG442LEDQ-GE3
DG442LDQ-T1-E3	DG442LEDQ-T1-GE3
DG442LDY-E3	DG442LEDY-GE3
DG442LDY-T1-E3	DG442LEDY-T1-GE3

Specification Comparison Table (Single 12 V):

PARAMETER	TEMP	DG441L, DG442L			DG441LE, DG442LE			UNIT
		TYP	MIN	MAX	TYP	MIN	MAX	
Analog Switch								
Analog Signal Range	Full		0	12		0	12	V
Drain-Source On-Resistance	Room	20		30	16		30	Ω
	-40 °C to 85 °C			40			40	
	-55 °C to 125 °C			45			45	
On-Resistance Match bet. Channels	Room	0.1		0.5	0.1		0.5	Ω
Switch Off Leakage Current I _{S(off)}	Room		-1	1		-1	1	nA
	-40 °C to 85 °C		-10	10		-10	10	
	-55 °C to 125 °C		-15	15		-15	15	
Switch Off Leakage Current I _{D(off)}	Room		-1	1		-1	1	nA
	-40 °C to 85 °C		-10	10		-10	10	
	-55 °C to 125 °C		-15	15		-15	15	
Channel On Leakage Current I _{D(on)}	Room		-1	1		-1	1	nA
	-40 °C to 85 °C		-10	10		-10	10	
	-55 °C to 125 °C		-15	15		-15	15	
Digital Control								
Input Current, V _{IN} Low	Room	0.01			0.01			μA
	-40 °C to 85 °C		-1	1		-1	1	
	-55 °C to 125 °C		-1.5	1.5		-1.5	1.5	
Input Current, V _{IN} High	Room							μA
	-40 °C to 85 °C		-1	1		-1	1	
	-55 °C to 125 °C		-1.5	1.5		-1.5	1.5	
Dynamic Characteristics								
Turn-On Time	Room	20		60	18		60	ns
	-40 °C to 85 °C			70			70	
	-55 °C to 125 °C			80			80	
Turn-Off Time	Room	12		35	18		35	ns
	-40 °C to 85 °C			45			45	
	-55 °C to 125 °C			50			50	
Charge Injection	Room	5			6.6			pC
Off Isolation	Room	71			68.4			dB
Crosstalk	Room	95			114			dB
Source Off Capacitance	Room	5						pF
Drain Off Capacitance	Room	6						pF
Drain On Capacitance	Room	15						pF
Power Supplies								
Positive Supply Current	Room	0.03			0.03			μA
	-40 °C to 85 °C			1			1	
	-55 °C to 125 °C			1.5			1.5	
Negative Supply Current	Room	0.002	-1		0.002	-1		μA
	-40 °C to 85 °C		-5			-5		
	-55 °C to 125 °C		-7.5			-7.5		
Ground Current	Room	0.002			0.002			μA
	-40 °C to 85 °C		-1			-1		
	-55 °C to 125 °C		-1.5			-1.5		

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT WWW.VISHAY.COM/DOC/91000

DG4051E, DG4052E, DG4053E

Enhanced Performance Products

Applications

Enhanced Performance

- Extended operation to 16 V single power supply and ± 8 V dual power supplies
- Lower switch on-resistance with improved tolerance
- Reduced switch leakage limits by 50 %
- Enhanced ESD / HBM from 2 kV to 2.5 kV
- Enhanced latch-up from 200 to 400 mA

- Automatic test equipment
- Process control and automation
- Data acquisition systems
- Meters and instruments
- Medical and healthcare systems
- Communication systems
- Battery powered systems
- Audio and video signal routing

New products are pin-compatible with current DG4051A, DG4052A and DG4053A series:

PACKAGE	EXISTING PART NUMBER	NEW ENHANCED PART NUMBER	EXISTING PART NUMBER	NEW ENHANCED PART NUMBER	EXISTING PART NUMBER	NEW ENHANCED PART NUMBER
miniQFN16	DG4051AEN-T1-E4	DG4051EEN-T1-GE4	DG4052AEN-T1-E4	DG4052EEN-T1-GE4	DG4053AEN-T1-E4	DG4053EEN-T1-GE4
TSSOP16	DG4051AEQ-T1-E3	DG4051EEQ-T1-GE3	DG4052AEQ-T1-E3	DG4052EEQ-T1-GE3	DG4053AEQ-T1-E3	DG4053EEQ-T1-GE3
SOIC16		DG4051EY-T1-GE3		DG4052EY-T1-GE3		DG4053EY-T1-GE3

Specification Comparison Table (Dual ± 5 V):

Parameter	Temperature °C	DG4051A, DG4052A, DG4053A			DG4051E, DG4052E, DG4053E			Unit
		Typ	Min	Max	Typ	Min	Max	
Analog Switch								
Analog Signal Range	Full		-5	5		-5	5	V
Drain-Source On-Resistance	Room	66		100	68		78	Ω
	(-40 to +85)			118			97	Ω
	(-40 to +125)			125			106	Ω
R _{DS(on)} Matching Between Channels	Room	3		6	0.91		6	Ω
	(-40 to +85)			8			6	Ω
	(-40 to +125)			10			6	Ω
On-Resistance Flatness	Room	12		16	10		17	Ω
	(-40 to +85)			18			19	Ω
	(-40 to +125)			20			20	Ω
Switch Off Leakage Current I _{S(off)}	Room	± 0.02	-1	1	± 0.05	-1	1	nA
	(-40 to +85)		-5	5		-5	5	nA
	(-40 to +125)		-50	50		-50	50	nA
Switch Off Leakage Current I _{D(off)}	Room	± 0.02	-1	1	± 0.05	-1	1	nA
	(-40 to +85)		-5	5		-5	5	nA
	(-40 to +125)		-50	50		-50	50	nA
Channel On Leakage Current I _{D(on)}	Room	± 0.02	-1	1	± 0.05	-1	1	nA
	(-40 to +85)		-5	5		-5	5	nA
	(-40 to +125)		-50	50		-50	50	nA
Digital Control								
Logic Low Input Voltage	Full			0.8			0.6	V
Logic High Input Voltage	Full		2.0			2.0		V
Input Current I _L	Full	0.01	-1	1	0.02	-1	1	uA
Input Current I _H	Full	0.01	-1	1	0.02	-1	1	uA
Dynamic Characteristics								
Transition Time	Room	36		110	72		130	ns
	(-40 to +85)			117	91		150	ns
	(-40 to +125)			127	99		160	ns
Enable Turn-On Time	Room	31		108	35		75	ns
	(-40 to +85)			114			80	ns
	(-40 to +125)			119			86	ns
Enable Turn-Off Time	Room	29		92	48		88	ns
	(-40 to +85)			98			95	ns
	(-40 to +125)			103			97	ns

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT WWW.VISHAY.COM/DOC?91000

DG4051E, DG4052E, DG4053E

Enhanced Performance Products



Specification Comparison Table (Dual +/- 5 V): (Continued):

Parameter	Full	DG4051A, DG4052A, DG4053A			DG4051E, DG4052E, DG4053E			Unit
		Typ	Min	Max	Typ	Min	Max	
Break-Before-Make Time	Room		1		23	1		ns
	(-40 to 85)			98	41	1		ns
	(-40 to 125)		1		53	13		ns
Charge Injection (worst of all parts)	Room	0.25			0.38			pC
BW	Room	330			308			MHz
	Room	450			353			
	Room	730			930			
Off Isolation DG4051E	Room	< -90			< -90	-108	-108	dB
	Room				-68	-59	-68	
	Room				-49	-38	-47	
Crosstalk DG4051E	Room	< -90			< -90	-95	-93	dB
	Room				-62	-63	-60	
	Room				-51	-45	-41	
Source Off Capacitance DG4051E	Room	3			2.2			pF
	Room	3			2.1			pF
	Room	3			2			pF
Drain Off Capacitance	Room	12			9.2			pF
	Room	7			4.8			pF
	Room	4			3.1			pF
Drain On Capacitance	Room	17			14.9			pF
	Room	13			10.0			pF
	Room	11			8.5			pF
Total Harmonic Distortion	Room	0.28			0.065			%
	Room	0.28			0.065			%
	Room	0.28			0.065			%
Power Supplies								
Power Supply Range	Room		-5	5		-5	5	V
Power Supply Current I+	Room	0.05		1	0.05		1	uA
	(-40 to 85)			10			10	uA
	(-40 to 125)			10			10	uA
Power Supply Current I-	Room	-0.05	-1		-0.05	-1		uA
	(-40 to 85)		-10			-10		uA
	(-40 to 125)		-10			-10		uA
Ground Current Ignd	Room	-0.05	-1		-0.05	-1		uA
	(-40 to 85)		-10			-10		uA
	(-40 to 125)		-10			-10		uA
Logic Supply Current IL	Room	0.05		1	0.05		1	uA
	(-40 to 85)			10			10	uA
	(-40 to 125)			10			10	uA

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT WWW.VISHAY.COM/DOC/91000



DG9408E, DG9409E

Enhanced Performance Products

Enhanced Performance

- Extended operation to 16 V single power supply and ± 8 V dual power supplies
- Reduced charge injection from 29 pF to 4.5 pF
- Parasitic on-capacitance reduced by 35 %
- Enhanced ESD / HBM from 2 kV to 2.5 kV
- Enhanced latch-up capability from 200 mA to 400 mA

Applications

- Automatic test equipment
- Data acquisition systems
- Meters and instruments
- Medical and healthcare systems
- Communication systems
- Audio and video signal routing
- Portable Meters

New products are pin-compatible with current DG9408, DG9409 series:

PACKAGE	EXISTING PART NUMBER	NEW ENHANCED PART NUMBER	EXISTING PART NUMBER	NEW ENHANCED PART NUMBER
QFN16	DG9408DN-T1-E4	DG9408EDN-T1-GE4	DG9409DN-T1-E4	DG9409EDN-T1-GE4

Specification Comparison Table (Single 12 V):

Parameter	Temperature °C	DG9408, DG9409			DG9408E, DG9409E			Unit
		Typ	Min	Max	Typ	Min	Max	
Analog Switch								
Analog Signal Range	-40 to +85		0	12		0	12	V
Drain-Source On-Resistance	Room	4		7	3.2		7	Ω
	-40 to +85			7.5			7.5	
R _{DS(on)} Matching Between Channels	Room			3.6			3.6	Ω
On-Resistance Flatness	Room			8			8	Ω
Switch Off Leakage Current I _{S(off)}	Room		-2	2		-2	2	nA
	-40 to +85		-15	15		-15	15	
Switch Off Leakage Current I _{D(off)}	Room		-2	2		-2	2	nA
	-40 to +85		-15	15		-15	15	
Channel On Leakage Current I _{D(on)}	Room		-2	2		-2	2	nA
	-40 to +85		-15	15		-15	15	
Digital Control								
Logic High Input Voltage	-40 to +85		2.4			2.4		V
Logic Low Input Voltage	-40 to +85			0.8			0.8	V
Input Current	-40 to +85		-1	1		-1	1	uA
Dynamic Characteristics								
Transition Time	Room	42		71	40		71	ns
	-40 to +85			75			75	
Break-Before-Make Time	Room	24	2		20	2		ns
	-40 to +85							
Enable Turn-On Time	Room	42		70	36		70	ns
	-40 to +85			75			75	
Enable Turn-Off Time	Room	24		44	24		44	ns
	-40 to +85			46			46	
Charge Injection	Room	29			4.5			pC
Off Isolation	Room	-80			-83			dB
Crosstalk	Room	-85			-89			dB
Source Off Capacitance (DG9408)	Room	21			17			pF
Source Off Capacitance (DG9409)	Room	23			16			
Drain Off Capacitance (DG9408)	Room	211			134			pF
Drain Off Capacitance (DG9409)	Room	112			67			
Drain On Capacitance (DG9408)	Room	238			154			pF
Drain On Capacitance (DG9409)	Room	137			86			
Power Supplies								
I+ Supply Current	Room			1			1	uA
I- Supply current	Room		-1			-1		uA
ESD/Latch-Up								
ESD-HBM	Room	2			2.5			kV
ESD-MM	Room				100			V
Latch-Up I-injection	Room	200			400			mA

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT WWW.VISHAY.COM/DOC?91000

DG9424E, DG9425E, DG9426E

Enhanced Performance Products



Enhanced Performance

- Extended operation to 16 V single power supply and ± 8 V dual power supplies
- Switch resistance reduced by 5 %
- Parasitic capacitance reduced by 25 %
- Enhanced ESD / HBM from 1 kV to 1.5 kV

Applications

- Automatic test equipment
- Data acquisition systems
- Meters and instruments
- Medical and healthcare systems
- Computer peripherals
- Audio and video signal routing

New products are pin-compatible with current DG9424, DG9425 and DG9426 series:

PACKAGE	EXISTING PART NUMBER	NEW ENHANCED PART NUMBER	EXISTING PART NUMBER	NEW ENHANCED PART NUMBER	EXISTING PART NUMBER	NEW ENHANCED PART NUMBER
TSSOP16	DG9424DQ-T1-E3	DG9424EDQ-T1-GE3	DG9425DQ-T1-E3	DG9425EDQ-T1-GE3	DG9426DQ-T1-E3	DG9426EDQ-T1-GE3

Specification Comparison Table (Dual +12 V / 0 V and $V_L = 5$ V):

Parameter	Temperature °C	DG9424, DG9425, DG9426			DG9424E, DG9425E, DG9426E			Unit
		Typ	Min	Max	Typ	Min	Max	
Analog Switch								
Analog Signal Range	Full		0	12		0	12	V
Drain-Source On-Resistance	Room	1.8		3	1.6		3	Ω
	(-40 to +85)			4			4	Ω
Switch Off Leakage Current I _{S(off)}	Room	-	-	-	-	-	-	nA
	(-40 to +85)	-	-	-	-	-	-	nA
Switch Off Leakage Current I _{D(off)}	Room	-	-	-	-	-	-	nA
	(-40 to +85)	-	-	-	-	-	-	nA
Channel On Leakage Current I _{D(on)}	Room	-	-	-	-	-	-	nA
	(-40 to +85)	-	-	-	-	-	-	nA
Digital Control								
Logic Low Input Voltage	Full			0.8			0.8	V
Logic High Input Voltage	Full		2.4			2.4		V
Input Current I _L	Full	0.01	-1	1	0.01	-1	1	uA
Input Current I _H	Full	0.01	-1	1	0.01	-1	1	uA
Dynamic Characteristics								
Enable Turn-On Time	Room	42		57	36		51	ns
	(-40 to +85)			65			65	ns
Enable Turn-Off Time	Room	28		42	20		35	ns
	(-40 to +85)			44			44	ns
Break-Before-Make Time	Room	2			2			ns
Charge Injection	Room	38			-29.2			pC
Off Isolation	Room	-56			-56			dB
Crosstalk	Room	-77			-96			dB
Source Off Capacitance	Room	49			30			pF
Drain Off Capacitance	Room	37			28			pF
Drain On Capacitance	Room	89			74			pF
Power Supplies								
Power Supply Current I+	Room	0.02		1	0.02		1	uA
	(-40 to +85)			5			5	uA
Power Supply Current I-	Room	-0.002	-1		-0.002	-1		uA
	(-40 to +85)		-5			-5		uA
Logic Supply Current I _L	Room	0.002		1	0.002		1	uA
	(-40 to +85)			5			5	uA
Ground Current I _{GND}	Room	-0.002	-1		-0.002	-1		uA
	(-40 to +85)		-5			-5		uA

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT WWW.VISHAY.COM/DOC?91000

DG9454E

Enhanced Performance Products



Enhanced Performance

- Extended operation to 16 V single power supply and ± 8 V dual power supplies
- 40 % faster turn-on time
- Enhanced ESD / HBM from 2 kV to 2.5 kV

Applications

- Games and goggles
- Process control and automation
- Data acquisition systems
- Meters and instruments
- Medical and healthcare systems
- Communication systems
- Battery powered systems

New products are pin-compatible with current DG9454:

PACKAGE	EXISTING PART NUMBER	NEW ENHANCED PART NUMBER
QFN16	DG9454EN-T1-E4	DG9454EEN-T1-GE4

Specification Comparison Table (Single 12 V):

PARAMETER	TEMP (°C)	DG9454			DG9454E			
		TYP	MIN	MAX	TYP	MIN	MAX	
Analog Switch								
Analog Signal Range	Full		0	12		0	12	V
Drain-Source On-Resistance	Room	80		120	85		103	Ω
	(-40 to 85)			137			125	Ω
	(-40 to 125)			143			133	Ω
R _{DS(on)} Matching Between Channels	Room	4		7	1.24		8	Ω
	(-40 to 85)			8			8	Ω
	(-40 to 125)			10			8	Ω
On-Resistance Flatness	Room	32		26	27		37	Ω
	(-40 to 85)			28			43	Ω
	(-40 to 125)			30			44	Ω
Switch Off Leakage Current I _{s(off)}	Room		-1	1		-1	1	nA
	(-40 to 85)		-5	5		-5	5	nA
	(-40 to 125)		-50	50		-50	50	nA
Switch Off Leakage Current I _{d(off)}	Room		-1	1		-1	1	nA
	(-40 to 85)		-5	5		-5	5	nA
	(-40 to 125)		-50	50		-50	50	nA
Channel On Leakage Current I _{d(on)}	)Room		-1	1		-1	1	nA
	(-40 to 85)		-5	5		-5	5	nA
	(-40 to 125)		-50	50		-50	50	nA
Digital Control								
Logic Low Input Voltage (V _L = 2.7 V)	Full			0.5			0.5	V
Logic High Input Voltage (V _L = 2.7 V)	Full		1.6			1.8		V
Input Current I _L	Full	0.01	-1	1	0.02	-1	1	μA
Input Current I _H	Full	0.01	-1	1	0.02	-1	1	μA
Dynamic Characteristics								
Transition Time	Room	80		135	79		119	ns
	(-40 to 85)			170	86		126	ns
	(-40 to 125)			205	94		134	ns
Enable Turn-On Time	Room	115		180	70		110	ns
	(-40 to 85)			215	76		116	ns
	(-40 to 125)			250	90		130	ns
Enable Turn-Off Time	Room	46		110	51		91	ns
	(-40 to 85)			145	54		94	ns
	(-40 to 125)			180	55		95	ns
Break-Before-Make Time	Room	37			17	1		ns
	(-40 to 85)		12		22	1		ns
	(-40 to 125)		12		27	1		ns
Charge Injection at V _g = 0 V, R _g = 0 (Ω)	Room	0.86			5.84			pC
Off Isolation	100 kHz	< -90			-95			dB
	1 MHz	-80			-85			dB
	10 MHz	-61			-65			dB

DG9454E

Enhanced Performance Products



Specification Comparison Table (Single 12 V): (Continued):

PARAMETER	TEMP (°C)	DG9454			DG9454E			
		TYP	MIN	MAX	TYP	MIN	MAX	
Dynamic Characteristics								
Crosstalk	100 kHz	< -90			-92			dB
	1 MHz	-81			-73			dB
	10 MHz	-65			-53			dB
Bandwidth, -3 dB	Room	540			356			MHz
Source Off Capacitance	Room	2			3.1			pF
Drain Off Capacitance	Room	3			4			pF
Drain On Capacitance	Room	6			8.8			pF
Total Harmonic Distortion	Room	0.01			0.075			%
Power Supplies								
Power Supply Current I+	Room	0.05		1	0.05		1	μA
	(-40 to 85)			10			10	μA
	(-40 to 125)			10			10	μA
Ground Current I _{GND}	Room	-0.05	-1		-0.05	-1		μA
	(-40 to 85)		-10			-10		μA
	(-40 to 125)		-10			-10		μA
Logic Supply Current I _L	Room	0.05		1	0.17		1	μA
	(-40 to 85)			10			10	μA
	(-40 to 125)			10			10	μA